

# MRSBulletin





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June 2020 Vol. 45 No. 6 mrs.org/bulletin

# Halide perovskite opto- and nanoelectronic materials and devices

# ALSO IN THIS ISSUE

Materials science for quantum information science and technology

# **CUSTOMIZED PRODUCTION ION IMPLANTERS**



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# 23rd International Conference on Ion Implantation Technology

September 20-24, 2020 | San Diego, California | The US Grant Hotel

# PREREGISTRATION OPENS MID-JULY

#### The International Conference on Ion Implantation Technology 2020 (IIT 2020) is the

23rd Conference in the biannual series focused on discussion of major challenges in current and emerging technologies related to implant/doping and annealing processes, device applications, equipment, metrology and modeling. The Conference offers an excellent opportunity for engineers and researchers in industry, research institutes and universities to present new results and to discuss ideas of new applications of ion implantation and annealing. The organizers welcome contributions from a wide range of topics, from fundamental research to industrial applications and equipment.

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## SCIENTIFIC PROGRAM

The five-day Conference will feature oral and poster presentations covering the following topics:

#### **Advanced Implant/Doping and Annealing Equipment**

#### **Annealing Technologies and Processes**

- Rapid Thermal Processing, Laser Annealing, Flash Annealing, SPE, New Activation Annealing
- Junction, Silicide, Contact and Dielectric Formation
- Lattice Damage and Defects

# **Device Applications for Implant/Doping and Annealing Processes**

- CMOS Devices, Memory Devices, Power Devices (SiC, GaN), RF-SOI, Image Sensors, IoT Devices, Photovoltaics, III-V Devices
- Integration with Other Fabrication Processes

#### Implant/Doping Technologies and Processes

- Ion Implantation, Plasma Doping, Gas and Solid Doping
- Junction Formation, MeV Implant, Materials Modification

# Metrologies for Implant/Doping and Annealing Processes:

- Physical and Electrical Characterization of 2D and 3D Structures
- Advanced Process Control

Modeling and Simulation of Implant/Doping and Annealing Processes

## **CONFERENCE VENUE**

San Diego, California, is often referred to as "America's Finest City" and for good reason! Known for its beautiful weather, pristine beaches, friendly people and plethora of entertainment, San Diego is a favorite travel destination for visitors across the globe. This great city has a huge variety of attractions—from famous destinations like the San Diego Zoo,

Sea World and Coronado Beach, to the 17 diverse museums of Balboa Park and the historic Gaslamp Quarter, San Diego has many dimensions to satisfy every traveler. A perfect blend of nature, city, suburbia and tourism make San Diego an ideal Conference and vacation destination.

For the most up-to-date information on IIT 2020, visit **mrs.org/iit2020**.

IIT 2020 is managed by



www.mrs.org/conference-services





## HALIDE PEROVSKITE OPTO- AND NANOELECTRONIC **MATERIALS AND DEVICES**



Halide perovskite materials and devices Sang II Seok and Tzung-Fang Guo, Guest Editors



431 Post-treatment techniques for highperformance perovskite solar cells

Shuang Xiao, Yu Li, Shizhao Zheng, and Shihe Yang



Photon recycling in halide perovskite solar cells for higher efficiencies

> Seungmin Lee, Kwang Choi, Chang Ha Min, Mun Young Woo, and Jun Hong Noh



Hole-conductor-free perovskite solar cells

Deyi Zhang, Yaoguang Rong, Yue Hu, Anyi Mei, and Hongwei Han



Advances in light-emitting metal-halide perovskite nanocrystals

> Liang-Jin Xu, Michael Worku, Qingquan He, and Biwu Ma



The underappreciated lone pair in halide perovskites underpins their unusual properties

> Douglas H. Fabini. Ram Seshadri. and Mercouri G. Kanatzidis



478 **Defects in halide perovskites:** The lattice as a boojum?

Sujit Kumar, Gary Hodes, and David Cahen

### TECHNICAL FEATURE



**Materials science for quantum information** science and technology

> MRS/Kavli Future of Materials Workshop: Solid-State Materials for Quantum Computing, 2019 MRS Spring Meeting

Christopher J.K. Richardson, Vincenzo Lordi, Shashank Misra, and Javad Shabani

# **Energy Quarterly**



Editorial

Whither computing

Subhash L. Shinde

#### 422 Energy Sector Analysis

Materials opportunities and challenges for low-energy computing: Thermal management and interconnects

Prachi Patel

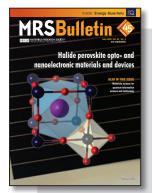
FEATURE EDITOR: Subhash L. Shinde

#### 424 Energy Sector Analysis

Reviving hydrogen as an energy carrier

Eva Karatairi

FEATURE EDITOR: Sabrina Sartori



#### ON THE COVER

Halide perovskite opto- and nanoelectronic materials and devices. The application of halide perovskites for photovoltaic solar cells and light-emitting diodes has rapidly expanded recently and is now being extended into nanoelectronics, including in thermoelectric, memory, and artificial synapse applications. Halide perovskites provide an excellent platform for optoelectronics with interesting optical, electrical, and magnetic properties. The articles in this issue overview halogen perovskites and devices for optoelectronic applications. The cover shows an AX<sub>12</sub> cuboctahedron that shares its edges with the BX<sub>6</sub> octahedron, the

classic perovskite structure, where A is a cation with a large ionic radius, B is a metal cation, and X is an anion. This structure is energetically stable and flexible enough to structurally accommodate a variety of elements. A perovskite solar cell mini-module is featured in the background. See the technical theme that begins on p. 427.



#### **COMING IN JULY 2020**

Rational design of nanomaterials for electrochemical water splitting

#### DEPARTMENTS



# OPINION

405 Material Matters

**Driving innovation with sports** 

Jan-Anders Mansson



## NEWS & ANALYSIS

- **Materials News** 
  - Noninvasive acoustic sensing diagnoses lithium-ion battery health

Boris Dyatkin

Controlled radical polymerization enables sense of texture in haptics

YuHao Liu

- In situ mechanical testing in an SEM performed at 1150°C with submicron resolution
  - Hortense Le Ferrand
- Empirical equations identify metal-organic frameworks with unprecedented hydrogen-storage capacity

Tianyu Liu

Complex microstructures emerge from chirality and competitive restrictions

Ahmad R. Kirmani

# 414 Science Policy

- The next 75 years: Symposium sparks upgrade to US policy model for R&D Judy Meiksin
- EU and Thailand address bio-circular-green-economy
- New call issued for joint Canada-UK projects on quantum technologies



# SOCIETY NEWS

- 413 MRS Journal Highlights
- 499 In remembrance: James F. Scott (1942–2020) Orlando Auciello and Ram S. Katiyar



# FEATURES

#### 500 Book Reviews

■ Biochemistry for Materials Science: Catalysts, Complexes and Proteins Akio Makishima

Reviewed by Somesh Mohapatra

- **Graphene: Important Results and Applications** George Wypych Reviewed by Jyothirmayee Aravind S.S.
- Foundations of Biomaterials Engineering Maria Cristina Tanzi, Silvia Farè, and Gabriele Candiani Reviewed by Jingjie Hu

504 Image Gallery **Look Again** 



# CAREER CENTRAL

502 **Career Feature** 

> US Immigration paths for scientific researchers: Part 2 Marco Pignone

ADVERTISERS IN THIS ISSUE	Page No.
American Elements High Voltage Engineering	

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The Materials Research Society (MRS), a not-for-profit scientific association founded in 1973 and headquartered in Warrendale, Pennsylvania, USA, promotes interdisciplinary materials research. Today, MRS is a growing, vibrant, member-driven organization of over 16,000 materials researchers spanning over 80 countries, from academia, industry, and government, and a recognized leader in the advancement of interdisciplinary materials research.

The Society's interdisciplinary approach differs from that of single-discipline professional societies because it promotes information exchange across many scientific and technical fields touching materials development. MRS conducts three major international annual meetings and also sponsors numerous single-topic scientific meetings. The Society recognizes professional and technical excellence and fosters technical interaction through University Chapters. In the international arena, MRS implements bilateral projects with partner organizations to benefit the worldwide materials community. The Materials Research Society Foundation helps the Society advance its mission by supporting various projects and initiatives.

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MRS Bulletin in care of the Journals Department, Cambridge University Press, 100 Brook Hill Drive, West Nyack, NY 10994-2113, USA. Printed in the U.S.A.

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